

## Silicon Power Transistors

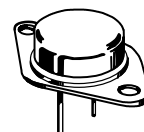
The MJ15023 and MJ15025 are PowerBase power transistors designed for high power audio, disk head positioners and other linear applications.

- High Safe Operating Area (100% Tested) —  
2 A @ 80 V
- High DC Current Gain —  
 $h_{FE} = 15$  (Min) @  $I_C = 8$  Adc

**PNP**  
**MJ15023**  
**MJ15025\***

\*Motorola Preferred Device

**16 AMPERE**  
**SILICON**  
**POWER TRANSISTORS**  
**200 AND 250 VOLTS**  
**250 WATTS**



**CASE 1-07**  
**TO-204AA**  
**(TO-3)**

### MAXIMUM RATINGS

Rating	Symbol	MJ15023	MJ15025	Unit
Collector-Emitter Voltage	$V_{CEO}$	200	250	Vdc
Collector-Base Voltage	$V_{CB0}$	350	400	Vdc
Emitter-Base Voltage	$V_{EBO}$	5		Vdc
Collector-Emitter Voltage	$V_{CEX}$	400		Vdc
Collector Current — Continuous Peak (1)	$I_C$	16 30		Adc
Base Current — Continuous	$I_B$	5		Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	250 1.43		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200		$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	0.70	$^\circ\text{C/W}$

(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle  $\leq$  10%.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 7

# MJ15023 MJ15025

## ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Sustaining Voltage (1) (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0)	MJ15023 MJ15025	V <sub>CEO(sus)</sub>	200 250	—
Collector Cutoff Current (V <sub>CE</sub> = 200 Vdc, V <sub>BE(off)</sub> = 1.5 Vdc) (V <sub>CE</sub> = 250 Vdc, V <sub>BE(off)</sub> = 1.5 Vdc)	MJ15023 MJ15025	I <sub>CEX</sub>	— —	250 250
Collector Cutoff Current (V <sub>CE</sub> = 150 Vdc, I <sub>B</sub> = 0) (V <sub>CE</sub> = 200 Vdc, I <sub>B</sub> = 0)	MJ15023 MJ15025	I <sub>CEO</sub>	— —	500 500
Emitter Cutoff Current (V <sub>CE</sub> = 5 Vdc, I <sub>B</sub> = 0)	Both	I <sub>EBO</sub>	—	500
<b>SECOND BREAKDOWN</b>				
Second Breakdown Collector Current with Base Forward Biased (V <sub>CE</sub> = 50 Vdc, t = 0.5 s (non-repetitive)) (V <sub>CE</sub> = 80 Vdc, t = 0.5 s (non-repetitive))		I <sub>S/b</sub>	5 2	— —
<b>ON CHARACTERISTICS</b>				
DC Current Gain (I <sub>C</sub> = 8 Adc, V <sub>CE</sub> = 4 Vdc) (I <sub>C</sub> = 16 Adc, V <sub>CE</sub> = 4 Vdc)		h <sub>FE</sub>	15 5	60 —
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 8 Adc, I <sub>B</sub> = 0.8 Adc) (I <sub>C</sub> = 16 Adc, I <sub>B</sub> = 3.2 Adc)		V <sub>CE(sat)</sub>	—	1.4 4.0
Base–Emitter On Voltage (I <sub>C</sub> = 8 Adc, V <sub>CE</sub> = 4 Vdc)		V <sub>BE(on)</sub>	—	2.2
<b>DYNAMIC CHARACTERISTICS</b>				
Current–Gain — Bandwidth Product (I <sub>C</sub> = 1 Adc, V <sub>CE</sub> = 10 Vdc, f <sub>test</sub> = 1 MHz)		f <sub>T</sub>	4	—
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f <sub>test</sub> = 1 MHz)		C <sub>ob</sub>	—	600

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2%.

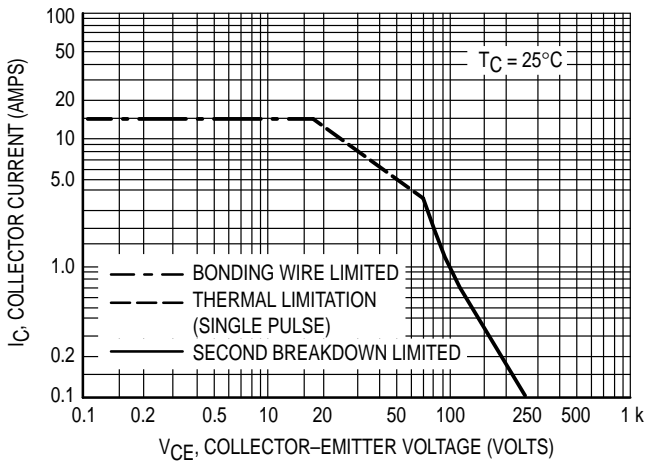


Figure 1. Active–Region Safe Operating Area

There are two limitations on the powerhandling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I<sub>C</sub> – V<sub>CE</sub> limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on T<sub>J(pk)</sub> = 200°C; T<sub>C</sub> is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

TYPICAL CHARACTERISTICS

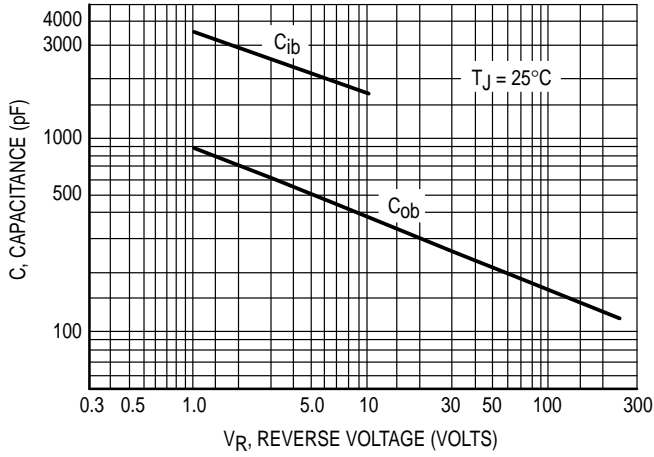


Figure 2. Capacitances

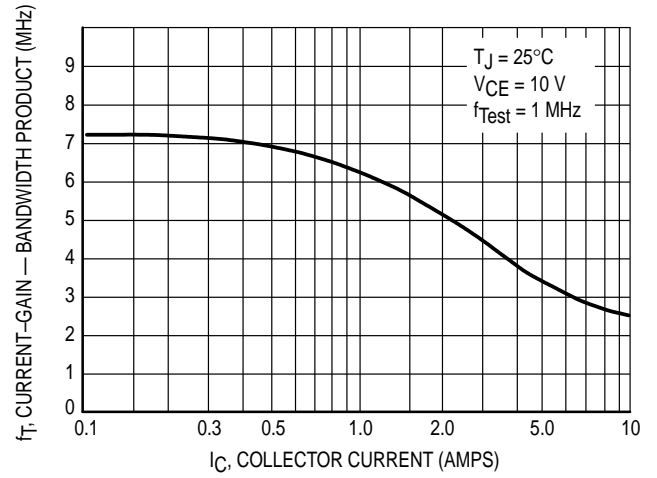


Figure 3. Current-Gain — Bandwidth Product

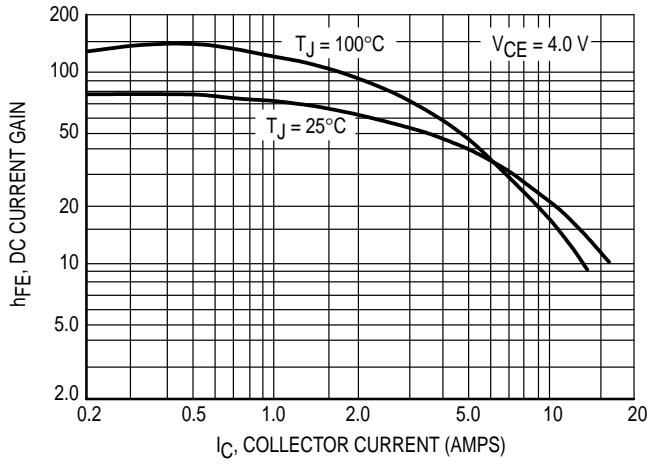


Figure 4. DC Current Gain

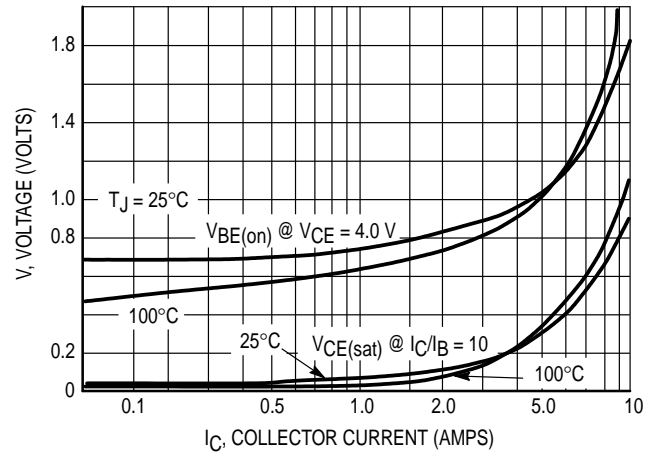
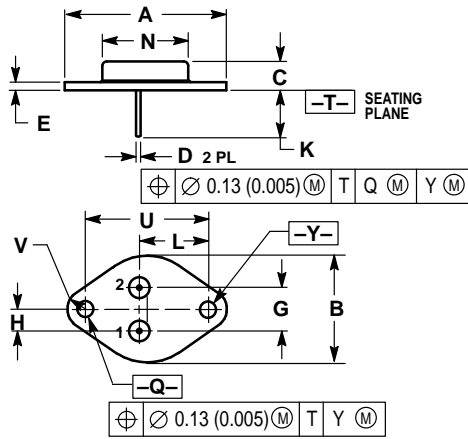


Figure 5. "On" Voltages

PACKAGE DIMENSIONS



- NOTES:  
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
 2. CONTROLLING DIMENSION: INCH.  
 3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	—	1.050	—	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	—	0.830	—	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:  
 PIN 1: BASE  
 2: EMITTER  
 CASE: COLLECTOR

CASE 1-07  
 TO-204AA (TO-3)  
 ISSUE Z

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How to reach us:  
 USA / EUROPE: Motorola Literature Distribution;  
 P.O. Box 20912; Phoenix, Arizona 85036. 1-800-441-2447

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki,  
 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE (602) 244-6609  
 INTERNET: http://Design-NET.com

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park,  
 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298

